TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

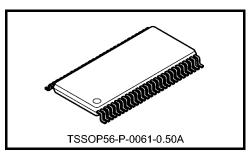
# **TC74VCX16827FT**

#### Low-Voltage 20-Bit Bus Buffer with 3.6-V Tolerant Inputs and Outputs

The TC74VCX16827FT is a high-performance CMOS 20-bit bus buffer. Designed for use in 1.8-V, 2.5-V or 3.3-V systems, it achieves high speed operation while maintaining the CMOS low power dissipation.

It is also designed with overvoltage tolerant inputs and outputs up to  $3.6\ V.$ 

The TC74VCX16827FT is composed of two 10-bit sections with separate output-enable signals. For either 10-bit buffer section, the two output-enable (10E1 and 10E2 or 20E1 and 20E2) inputs must both be low for the corresponding Y outputs to be active. When the  $\overline{\rm OE}$  input is high, the outputs are in a high-impedance state. This device is designed to be used with 3-state memory address drivers, etc.



Weight: 0.25 g (typ.)

All inputs are equipped with protection circuits against static discharge.

#### **Features**

- Low-voltage operation: V<sub>CC</sub> = 1.8 to 3.6 V
- High-speed operation:  $t_{pd} = 2.5 \text{ ns (max) (V}_{CC} = 3.0 \text{ to } 3.6 \text{ V)}$

 $t_{pd} = 3.0 \text{ ns (max) (VCC} = 2.3 \text{ to } 2.7 \text{ V}$ 

 $t_{pd} = 6.0 \text{ ns (max) (V}_{CC} = 1.8 \text{ V})$ 

- Output current:  $I_{OH}/I_{OL} = \pm 24 \text{ mA (min)} (V_{CC} = 3.0 \text{ V})$ 
  - :  $I_{OH}/I_{OL} = \pm 18$  mA (min) ( $V_{CC} = 2.3$  V)

:  $I_{OH}/I_{OL} = \pm 6$  mA (min) ( $V_{CC} = 1.8$  V)

- Latch-up performance: -300 mA
- ESD performance: Machine model  $\geq \pm 200 \text{ V}$

Human body model ≥ ±2000 V

- Package: TSSOP
- 3.6-V tolerant function and power-down protection provided on all inputs and outputs

### Pin Assignment (top view)

#### 56 10E2 10E1 1Y1 2 55 1A1 1Y2 3 54 1A2 GND 4 **GND** 53 1Y3 52 1A3 6 1Y4 51 1A4 $V_{CC}$ 50 $V_{CC}$ 1Y5 8 49 1A5 1Y6 9 48 1A6 1Y7 10 47 1A7 GND 11 GND 46 1Y8 12 1A8 45 1Y9 13 1A9 1Y10 14 1A10 43 2Y1 15 42 2A1 2Y2 16 2A2 2Y3 17 2A3 40 GND 18 GND 39 2Y4 19 2A4 38 2Y5 20 2A5 37 2Y6 21 2A6 36 $V_{CC}$ 22 35 $V_{CC}$ 2Y7 23 34 2A7 2Y8 24 2A8 33 GND 25 GND 32 2Y9 26 31 2A9 2Y10 27 2A10 30 2<del>OE1</del> 28 2OE2 29

### **IEC Logic Symbol**

10E1 - 10E2 - 20E1 - 20E2 -	1 56 28 29 N	& &	EN1 EN2		
1A1 - 1A2 - 1A3 - 1A4 -	55 54 52 51 49		1 1 🗸	2 3 5 6	1Y1 1Y2 1Y3 1Y4
1A5 - 1A6 - 1A7 -	48 47			9 10	1Y5 1Y6 1Y7
1A8 - 1A9 -	45 44			12 13 14	1Y8 1Y9
1A10 - 2A1 - 2A2 -	43 42 41		1 2 🗸	15 16	1Y10 2Y1 2Y2
2A3 - 2A4 -	40 38 37			17 19 20	2Y3 2Y4
2A5 - 2A6 - 2A7 -	36 34			21 23	2Y5 2Y6 2Y7
2A8 - 2A9 -	33 31			24 26	2Y8 2Y9
2A10 -	30	+		27	2Y10

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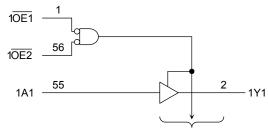
### Truth Table (each 10-bit latch)

	Input	Output	
OE1	OE2	Α	Y
L	L	L	L
L	L	Н	Н
Н	Х	Х	Z
Х	Н	Х	Z

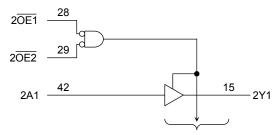
X: Don't care

Z: High impedance

### **System Diagram**



To nine other channels



3

To nine other channels

#### **Absolute Maximum Ratings (Note 1)**

Characteristics	Symbol	Rating	Unit
Power supply voltage	$V_{CC}$	-0.5 to 4.6	V
DC input voltage	V <sub>IN</sub>	-0.5 to 4.6	V
		-0.5 to 4.6 (Note 2)	
DC output voltage	$V_{OUT}$	–0.5 to V <sub>CC</sub> + 0.5	V
		(Note 3)	
Input diode current	I <sub>IK</sub>	<b>−50</b>	mA
Output diode current	lok	±50 (Note 4)	mA
DC output current	lout	±50	mA
Power dissipation	$P_{D}$	400	mW
DC V <sub>CC</sub> /ground current per supply pin	I <sub>CC</sub> /I <sub>GND</sub>	±100	mA
Storage temperature	T <sub>stg</sub>	-65 to 150	°C

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 2: OFF state

Note 3: High or low state. IOUT absolute maximum rating must be observed.

Note 4:  $V_{OUT} < GND, V_{OUT} > V_{CC}$ 

#### **Operating Ranges (Note 1)**

Characteristics	Symbol	Rating	Unit	
Power supply voltage	V <sub>CC</sub>	1.8 to 3.6	V	
1 ower supply voltage	<b>VCC</b>	1.2 to 3.6 (Note 2)	V	
Input voltage	VIN	-0.3 to 3.6	V	
Output voltage	V <sub>OUT</sub>	0 to 3.6 (Note 3)	V	
Output voltage	VOU1	0 to V <sub>CC</sub> (Note 4)	V	
		±24 (Note 5)		
Output current	I <sub>OH</sub> /I <sub>OL</sub>	±18 (Note 6)	mA	
		±6 (Note 7)		
Operating temperature	T <sub>opr</sub>	-40 to 85	°C	
Input rise and fall time	dt/dv	0 to 10 (Note 8)	ns/V	

Note 1: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either VCC or GND.

Note 2: Data retention only

Note 3: OFF state

Note 4: High or low state

Note 5:  $V_{CC} = 3.0 \text{ to } 3.6 \text{ V}$ 

Note 6:  $V_{CC} = 2.3 \text{ to } 2.7 \text{ V}$ 

Note 7:  $V_{CC} = 1.8 \text{ V}$ 

Note 8:  $V_{IN} = 0.8$  to 2.0 V,  $V_{CC} = 3.0$  V



### **Electrical Characteristics**

### DC Characteristics (Ta = -40 to 85°C, 2.7 V < $V_{CC} \leq 3.6 \ V)$

Characteristics		Symbol	Test	Test Condition		Min	Max	Unit
	H-level	V <sub>IH</sub>		_	V <sub>CC</sub> (V)	2.0		
Input voltage	L-level	VIL			2.7 to 3.6		0.8	V
	L-ievei	VIL		I <sub>OH</sub> = -100 μA	2.7 to 3.6	V <sub>CC</sub> – 0.2	— — — — — — — — — — — — — — — — — — —	
	H-level	V <sub>OH</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>II</sub>	I <sub>OH</sub> = -12 mA	2.7	2.2	_	
		011		I <sub>OH</sub> = -18 mA	3.0	2.4	_	
Output voltage				I <sub>OH</sub> = -24 mA	3.0	2.2	_	V
			V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OL</sub> = 100 μA	2.7 to 3.6	_	0.2	
	Lievel	.,		I <sub>OL</sub> = 12 mA	2.7	_	0.4	
	L-level	V <sub>OL</sub>		I <sub>OL</sub> = 18 mA	3.0	_	0.4	
				I <sub>OL</sub> = 24 mA	3.0	_	0.55	
Input leakage curre	nt	I <sub>IN</sub>	V <sub>IN</sub> = 0 to 3.6 V		2.7 to 3.6	_	±5.0	μА
3-state output OFF	state current	I <sub>OZ</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub> V <sub>OUT</sub> = 0 to 3.6 V		2.7 to 3.6	_	±10.0	μА
Power-off leakage current I <sub>OI</sub>		I <sub>OFF</sub>	V <sub>IN</sub> , V <sub>OUT</sub> = 0 to 3.6 V		0	_	10.0	μА
			V <sub>IN</sub> = V <sub>CC</sub> or GND		2.7 to 3.6	_	20.0	
Quiescent supply c	urrent	Icc	$V_{CC} \le (V_{IN}, V_{OUT}) \le$	V <sub>CC</sub> ≤ (V <sub>IN</sub> , V <sub>OUT</sub> ) ≤ 3.6 V		_	±20.0	μΑ
Increase in I <sub>CC</sub> per	input	Δlcc	$V_{IH} = V_{CC} - 0.6 V$ (pe	er input)	2.7 to 3.6	_	750	

### DC Characteristics (Ta = -40 to 85°C, 2.3 V $\leq$ V<sub>CC</sub> $\leq$ 2.7 V)

Character	Characteristics S		Test Condition		V <sub>CC</sub> (V)	Min	Max	Unit	
L	H-level	V <sub>IH</sub>		_	2.3 to 2.7	1.6	_	V	
Input voltage	L-level	V <sub>IL</sub>		_	2.3 to 2.7	_	0.7	V	
				$I_{OH} = -100 \mu A$	2.3 to 2.7	V <sub>CC</sub> - 0.2	_		
	H-level	Voh	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	$I_{OH} = -6 \text{ mA}$	2.3	2.0	_		
				I <sub>OH</sub> = -12 mA	2.3	1.8	_		
Output voltage			I <sub>OH</sub> = -18 mA	2.3	1.7	_	V		
			$V_{IN} = V_{IH}$ or $V_{IL}$	$I_{OL} = 100 \mu A$	2.3 to 2.7	_	0.2		
	L-level	V <sub>OL</sub>		$V_{IN} = V_{IH} \ or \ V_{IL}$	I <sub>OL</sub> = 12 mA	2.3	_	0.4	
				I <sub>OL</sub> = 18 mA	2.3	_	0.6		
Input leakage curre	ent	I <sub>IN</sub>	V <sub>IN</sub> = 0 to 3.6 V		2.3 to 2.7	_	±5.0	μА	
3-state output OFF state current		loz	$V_{IN} = V_{IH}$ or $V_{IL}$	$V_{IN} = V_{IH}$ or $V_{IL}$			±10.0	^	
		loz	V <sub>OUT</sub> = 0 to 3.6 V		2.3 to 2.7		±10.0	μА	
Power-off leakage	current	loff	V <sub>IN</sub> , V <sub>OUT</sub> = 0 to 3.6 V		0		10.0	μΑ	
Quiescent supply of	current	loo	V <sub>IN</sub> = V <sub>CC</sub> or GND		2.3 to 2.7		20.0	^	
Quiescerit supply t	Julieni	Icc	$V_{CC} \le (V_{IN}, V_{OUT}) \le 3.6 \text{ V}$		2.3 to 2.7	_	±20.0	μА	



### DC Characteristics (Ta = -40 to $85^{\circ}$ C, $1.8 \text{ V} \leq \text{V}_{CC} < 2.3 \text{ V}$ )

Characteristics		Symbol	Test Condition		V <sub>CC</sub> (V)	Min	Max	Unit
lanut valtara	H-level	V <sub>IH</sub>	_		1.8 to 2.3	0.7 × V <sub>CC</sub>	_	V
Input voltage	L-level	V <sub>IL</sub>	_	_	1.8 to 2.3	_	0.2 × V <sub>CC</sub>	V
	H-level	VoH	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	$I_{OH} = -100 \mu A$	1.8	V <sub>CC</sub> - 0.2		
Output voltage				I <sub>OH</sub> = -6 mA	1.8	1.4	_	V
	L-level	V <sub>OL</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	$I_{OL} = 100 \mu A$	1.8		0.2	
	L-IEVEI	VOL	AIM - AIH OL AIL	$I_{OL} = 6 \text{ mA}$	1.8		0.3	
Input leakage currer	nt	I <sub>IN</sub>	V <sub>IN</sub> = 0 to 3.6 V		1.8		±5.0	μΑ
3-state output OFF state current		I <sub>OZ</sub>	$V_{IN} = V_{IH}$ or $V_{IL}$ $V_{OUT} = 0$ to 3.6 V		1.8		±10.0	μА
Power-off leakage c	ower-off leakage current I <sub>OFF</sub> V <sub>IN</sub> , V <sub>OUT</sub> = 0 to 3.6 V		0	_	10.0	μΑ		
Quiggoont gunnly or			V <sub>IN</sub> = V <sub>CC</sub> or GND		1.8	_	20.0	^
Quiescent supply cu	inent	Icc	$V_{CC} \le (V_{IN}, V_{OUT}) \le 3.6 \text{ V}$		1.8	_	±20.0	μА

### AC Characteristics (Ta = -40 to 85°C, input: $t_r = t_f = 2.0$ ns, $C_L = 30$ pF, $R_L = 500$ $\Omega$ ) (Note 1)

Characteristics	Symbol	Test Condition	., .,	Min	Max	Unit
			V <sub>CC</sub> (V)			
	t <sub>pLH</sub>		1.8	1.5	6.0	
Propagation delay time	t <sub>pHL</sub>	Figure 1, Figure 2	$2.5 \pm 0.2$	1.0	3.0	ns
	ΨП		$3.3 \pm 0.3$	0.8	2.5	
	t		1.8	1.5	9.8	
3-state output enable time	t <sub>pZL</sub> t <sub>pZH</sub>	Figure 1, Figure 3	$2.5\pm0.2$	1.0	4.9	ns
			$3.3 \pm 0.3$	0.8	3.8	
	4		1.8	1.5	7.6	
3-state output disable time	t <sub>pLZ</sub>	Figure 1, Figure 3	$2.5 \pm 0.2$	1.0	4.2	ns
	t <sub>pHZ</sub>		$3.3 \pm 0.3$	8.0	3.7	
	<b>.</b>		1.8	_	0.5	
Output to output skew	tosLH	(Note 2)	$2.5\pm0.2$	_	0.5	ns
	tosHL		$3.3 \pm 0.3$		0.5	

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Note 1: For  $C_L = 50$  pF, add approximately 300 ps to the AC maximum specification.

Note 2: Parameter guaranteed by design.

 $(t_{OSLH} = |t_{PLHm} - t_{PLHn}|, \, t_{OSHL} = |t_{PHLm} - t_{PHLn}|)$ 



## Dynamic Switching Characteristics

(Ta = 25°C, input:  $t_r = t_f = 2.0 \text{ ns}, C_L = 30 \text{ pF}, R_L = 500 \Omega$ )

Characteristics	Symbol	Test Condition	V <sub>CC</sub> (V)	Тур.	Unit
		$V_{IH} = 1.8 \text{ V}, V_{IL} = 0 \text{ V}$ (Not		0.25	
Quiet output maximum dynamic VOI	V <sub>OLP</sub>	$V_{IH} = 2.5 \text{ V}, V_{IL} = 0 \text{ V}$ (Not	2.5	0.6	V
aynamic roll		V <sub>IH</sub> = 3.3 V, V <sub>IL</sub> = 0 V (Not	9) 3.3	0.8	
	V <sub>OLV</sub>	$V_{IH} = 1.8 \text{ V}, V_{IL} = 0 \text{ V}$ (Not	9) 1.8	-0.25	
Quiet output minimum dynamic V <sub>OI</sub>		$V_{IH} = 2.5 \text{ V}, V_{IL} = 0 \text{ V}$ (Not	2.5	-0.6	V
, 01		$V_{IH} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$ (Not	3.3	-0.8	
		$V_{IH} = 1.8 \text{ V}, V_{IL} = 0 \text{ V}$ (Not	1.8	1.5	
Quiet output minimum dynamic V <sub>OH</sub>		$V_{IH} = 2.5 \text{ V}, V_{IL} = 0 \text{ V}$ (Not	2.5	1.9	V
, on		$V_{IH} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$ (Not	9) 3.3	2.2	

Note: Parameter guaranteed by design.

### **Capacitive Characteristics (Ta = 25°C)**

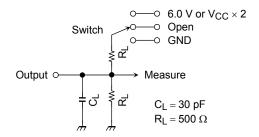
Characteristics	Symbol	Test Condition		Тур.	Unit
Characteristics	Syllibol	rest Condition	V <sub>CC</sub> (V)	τyp.	Offic
Input capacitance	C <sub>IN</sub>	_	1.8, 2.5, 3.3	6	pF
Output capacitance	C <sub>OUT</sub>	_	1.8, 2.5, 3.3	7	pF
Power dissipation capacitance	C <sub>PD</sub>	f <sub>IN</sub> = 10 MHz (Not	9) 1.8, 2.5, 3.3	20	pF

Note: C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/20 \text{ (per bit)}$ 

### **AC Test Circuit**



Parameter	Switch			
t <sub>pLH</sub> , t <sub>pHL</sub>	Open			
t <sub>pLZ</sub> , t <sub>pZL</sub>	$ \begin{array}{cccccccccccccccccccccccccccccccccccc$			
t <sub>pHZ</sub> , t <sub>pZH</sub>	GND			

Figure 1

### **AC Waveform**

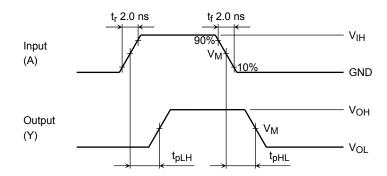


Figure 2 t<sub>pLH</sub>, t<sub>pHL</sub>

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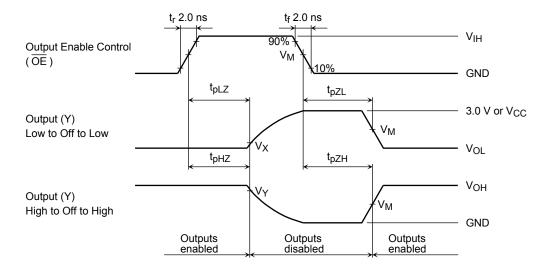


Figure 3  $\;t_{\text{pLZ}},\,t_{\text{pHZ}},\,t_{\text{pZL}},\,t_{\text{pZH}}$ 

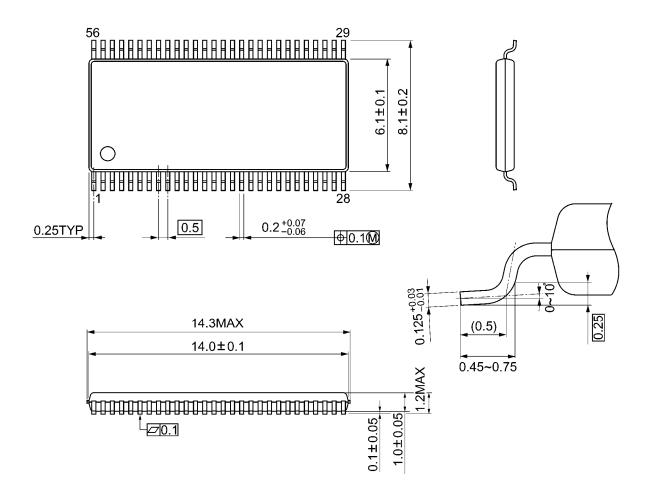
Symbol		V <sub>CC</sub>	
Syllibol	$3.3\pm0.3~\textrm{V}$	$2.5\pm0.2\textrm{V}$	1.8 V
$V_{IH}$	2.7 V	V <sub>CC</sub>	V <sub>CC</sub>
V <sub>M</sub>	1.5 V	V <sub>CC</sub> /2	V <sub>CC</sub> /2
VX	V <sub>OL</sub> + 0.3 V	V <sub>OL</sub> + 0.15 V	V <sub>OL</sub> + 0.15 V
$V_{Y}$	V <sub>OH</sub> – 0.3 V	V <sub>OH</sub> – 0.15 V	V <sub>OH</sub> – 0.15 V

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TC74VCX16827FT

### **Package Dimensions**

TSSOP56-P-0061-0.50A Unit: mm



Weight: 0.25 g (typ.)

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